## Product Description

The Sirenza SPM-2045 is a passive mixer designed for systems that require high linearity down- or up-conversion. It employs proprietary silicon FETs with proven reliable core-and-wire baluns. It operates efficiently over a wide range of Local Oscillator powers, with input third order intercept remaining approximately $15-18 \mathrm{~dB}$ above LO power over this range. This product is packaged in a standard surface mount module for excellent RF performance.

## Functional Block Diagram



## SPM-2045

High Linearity Passive FET Mixer


## Product Features

- Excellent linearity.
- Efficient operation over wide LO power range.
- Well behaved over variations in frequency, LO power, and port match.


## Applications

- PCS, DCS, UMTS upconverters and downconverters


## Product Specifications: Down-converter

Test Conditions: FLO $=1.8 \mathrm{GHz}$ FIF $=150 \mathrm{MHz}$ Frf $=1.95 \mathrm{GHZ}$ Plo $=17 \mathrm{dBm}$

| Parameters | Test Conditions | Unit | Min. | Typ. |  |
| :--- | :--- | :---: | :---: | :---: | :---: |
| RF Input Frequency Range |  | GHz | 1.7 |  | 2.3 |
| LO Frequency |  | GHz | 1.7 |  | 2.3 |
| IF Output Frequency |  | MHz | 50 |  | 500 |
| RF Return Loss | Frf $=1.9 \mathrm{GHz}$ | dB |  | 14 |  |
| LO Return Loss | Flo $=1.7 \mathrm{GHz}$ | dB |  | 5 |  |
| IF Return Loss | Fif= 200 MHz | dB |  | 14 |  |
| Conversion Loss | 2 GHz |  |  | 7.5 | 10 |
| SSB Noise Figure |  | dBm |  | 7.5 | 10 |
| TOI (Input) | $\mathrm{Plo}=14 \mathrm{dBm}$ | dBm |  | 28 |  |
|  | $\mathrm{Plo}=17 \mathrm{dBm}$ | dBm |  | 31 |  |
|  | $\mathrm{Plo}=20 \mathrm{dBm}$ | dBm |  | 20 |  |
| P1dB (input) | $\mathrm{Plo}=17 \mathrm{dBm}$ | dB |  | 30 |  |
| LO-RF isolation | 2 GHz | dB |  | 30 |  |
| LO-IF isolation | 2 GHz | dB |  | 35 |  |
| RF-IF isolation | 2 GHz |  |  |  |  |

[^0]Product Specifications: Up-converter
Test Conditions: $\mathrm{FLO}=1.8 \mathrm{GHz}$ FIF $=150 \mathrm{MHz}$ Frf $=1.95 \mathrm{GHZ}$ Plo $=17 \mathrm{dBm}$

| Parameters | Test Conditions | Unit | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| RF Output Frequency Range |  | GHz | 1.7 |  | 2.3 |
| LO Frequency |  | GHz | 1.7 |  | 2.3 |
| IF Input Frequency |  | MHz | 40 |  | 300 |
| RF Return Loss | Frf $=1.9 \mathrm{GHz}$ | dB |  | 14 |  |
| LO Return Loss | $\mathrm{Flo}=1.7 \mathrm{GHz}$ | dB |  | 5 |  |
| IF Return Loss | Fif=200 MHz | dB |  | 14 |  |
| Conversion Loss |  |  |  | 8 | 10 |
| TOI (Input) | $\mathrm{Plo}=14 \mathrm{dBm}$ | dBm |  | 23 |  |
|  | $\mathrm{Plo}=17 \mathrm{dBm}$ | dBm |  | 27 |  |
|  | Plo $=20 \mathrm{dBm}$ | dBm |  | 30 |  |
| P1dB (input) | $\mathrm{Plo}=17 \mathrm{dBm}$ | dBm |  | 20 |  |

## Absolute Maximum Ratings

| Parameters | Value | Unit |
| :--- | :---: | :---: |
| RF Input | +15 | dBm |
| LO Input | +21 | dBm |
| IF Input | -40 to +85 | dBm |
| Operating Temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | Operation of this device beyond any one of these limits may <br> cause permanent damage. For reliable continuous operation the <br> device voltage and current must not exceed the maximum oper- <br> ating values specified in the table on page one. |  |

The SPM-2045 mixer is a MOSFET based high performance mixer designed for high linearity frequency conversion in the 2 GHz band. This mixer features a wide latitude in LO power requirements. Conversion loss remains quite constant between 10 dBm and 20 dBm of LO power. Third Order Intercept is approximately proportional to the LO drive. This means that this mixer can be used to replace a wide variety of mixers requiring a variety of LO powers.

The graphs on the following pages illustrate the performance of the SPM-2045 over a variety of operating conditions. In order to duplicate these performance tests, the following precautions should be observed:
-The mixer should be presented with good return losses at all ports by using isolators or attenuators. This is especially true of the LO port, because of the poor return loss of this port. If ripple is seen in a frequency sweep, it is likely due to reflections caused by poor VSWR in a cable leading up to the device.
-The presence of harmonics in the LO can cause changes in TOI.
-Be aware that signals of many different frequencies exist at the output of the mixer, and any one can potentially cause the spectrum analyzer to generate intermod.
-When measuring TOI, make sure the two generators supplying the RF signal are not interacting, causing intermod themselves.


These graphs show mixer conversion loss vs. frequency, with both low-side LO excitation (LO frequency below the RF frequency) and high side excitation (LO frequency above the RF frequency). Operation both as a down-converter and an upconverter is shown, with LO powers of 14,17 , and 20 dBm . In all cases, the IF frequency is 150 MHz .


These graphs show mixer Third Order Intercept (TOI) vs. frequency referenced to the input of the mixer (that is, referenced to the RF port in the case off a down-converter, or the IF port in the case of an up-converter), with both low-side LO excitation (LO frequency below the RF frequency) and high side excitation (LO frequency above the RF frequency). Operation both as a down-converter and an up-converter is shown, with LO powers of 14,17 , and 20 dBm . In all cases, the IF frequency is 150 MHz . The RF power used in measuring third order intercept is +4 dBm . Note that third order products closely follow the expected $3: 1$ slope.


The contour graphs show mixer input TOI and conversion loss over a variety of RF and LO frequencies. These contour graphs can be used to assess the suitability of these mixers over a variety of frequencies of operation. Note that constant IF frequency curves can be overlaid as diagonal lines. Also shown are graphs of TOI and insertion loss vs. temperature. These curves were measured down-converter mode.







The isolation graph shows port isolation with a 2 GHz LO at 17 dB .
Half IF response is measured by applying RF signals ( 10 dBm amplitude) 100 MHz above or below the LO, and measuring the level of the undesired IF component at 200 MHz .



Package Dimensions


Part Number Ordering Information

| Part Number | Reel Size | Devices/Reel |
| :---: | :---: | :---: |
| SPM-2045 | $13^{\prime \prime}$ | 1000 |





## Sensitivity to Port Match

These graphs demonstrate the sensitivity of the linearity of the SPM-2045 to the impedance of the source which drives the RF port, and the load that the IF port sees. In this case, the mixer is operated as a down-converter with LO drive of 17dBm and an IF frequency of 150 MHz . Three LO frequencies are shown.

In the left graph, a variable-length 50 ohm transmission line ("trombone") is placed between the IF port of the mixer and a 2 dB , open-circuited attenuator to provide a 4 dB return loss to the IF port. The length of the transmission line is changed to vary the phase of the reflection coefficient, thus providing a variable impedance. This graph shows how the input TOI varies with the phase of the reflection coefficient. Notice that significant degradation in TOI can occur with mismatch, depending on the phase of the mismatch.

In the right graph, a double-stub tuner is placed between the RF source and the mixer in order to provide a non- 50 ohm impedance to the RF port. The stub separation was adjusted to provide a reflection coefficient of approximately -4 dB . The tuner length was changed to vary the phase of the reflection coefficient, thus providing a variable impedance. This graph shows how the input TOI varies with the phase of the reflection coefficient on the RF port. Note that the TOI is very tolerant of variations in load impedance, showing a change of only 3 dB .

## Demo Test Board Schematic

## SPM Evaluation Board



Recommended connectors:
Johnson 142-0701-851 SMA end-launch connectors (or equivalent)


[^0]:    The information provided herein is believed to be reliable at press time. Sirenza Microdevices assumes no responsibility for inaccuracies or ommisions.
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